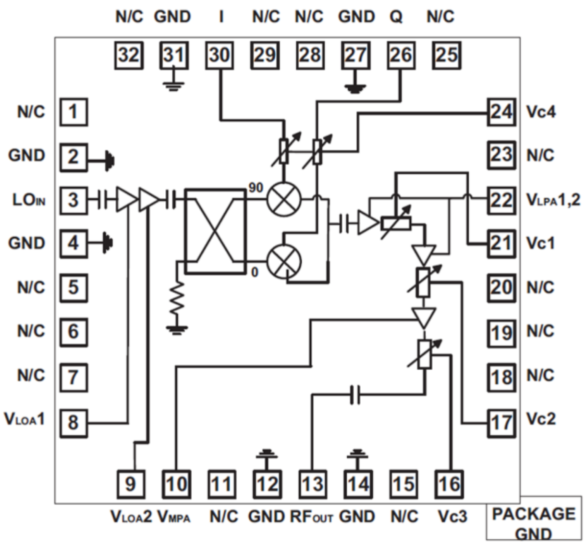
RFUV1003

GaAs MMIC IQ UpConverter
12GHz to 16GHz

Package: QFN, 32-pin,
5mm x 5mm x 0.95mm

RFMD's RFUV1003 is a 12GHz to 16GHz GaAs pHEMT upconverter, incorporating an integrated LO buffer amplifier, a balanced single-side band (image rejection) mixer followed by a variable gain amplifier and DC decoupling capacitors. The combination of high performance part and low cost packaging makes the RFUV1003 a cost effective solution, ideally suited to both current and next generation Point-to-Point and VSAT applications. RFUV1003 is packaged in a 5mm x 5mm QFN to simplify both system level board design and volume assembly.



Functional Block Diagram

Features

- RF Frequency: 12GHz to 16GHz
- LO Frequency: 8GHz to 20GHz
- IF Frequency: DC to 4GHz
- Maximum Conversion Gain: 23dB
- Minimum Conversion Gain: -10dB
- Noise Figure (Maximum Gain): 11dB
- Noise Figure (Minimum Gain): 17dB
- OIP3 (Maximum Gain): +28dBm
- OIP3 (Minimum Gain): +12dBm
- Image Rejection: 20dBc

Applications

- Point-to-Point
- VSAT

Ordering Information

RFUV1003S2	Sample bag with 2 pieces
RFUV1003SB	Bag with 5 pieces
RFUV1003SQ	Bag with 25 pieces
RFUV1003SR	7" Reel with 100 pieces
RFUV1003TR7	7" Reel with 750 pieces
RFUV1003TR13	13" Reel with 2500 pieces
RFUV1003PCK-410	Evaluation Board with 2-piece sample bag

RF Micro Devices Inc. 7628 Thorndike Road, Greensboro, NC 27409-9421
For sales or technical support, contact RFMD at +1.336.678.5570 or customerservice@rfmd.com.
DS140213

Absolute Maximum Ratings

Parameter	Rating	Unit
LPA Drain Voltage Vd	6	V
LOA Drain Voltage	6	V
RF Input Power	15	dBm
LO Input Power	15	dBm
T_{OPER}	-40 to +85	°C
T_{STOR}	-65 to +150	°C
ESD Human Body Model	Class 1A	

Caution! ESD sensitive device.

RFMD Green: RoHS compliant per EU Directive 2011/65/EU, halogen free per IEC 61249-2-21, <1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony solder.

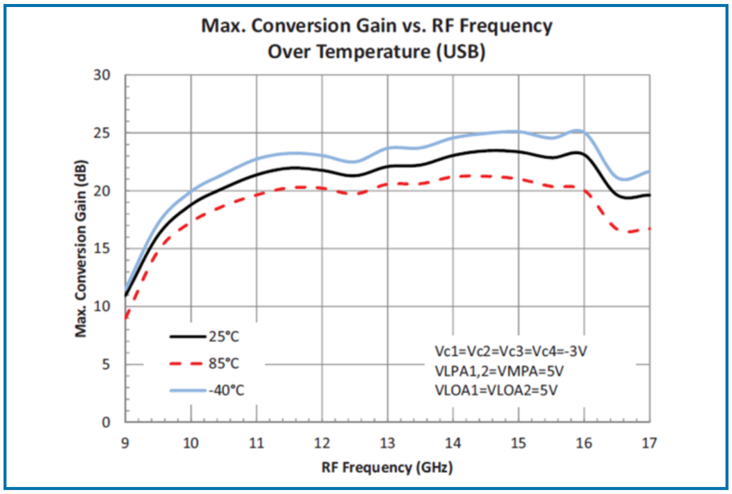
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

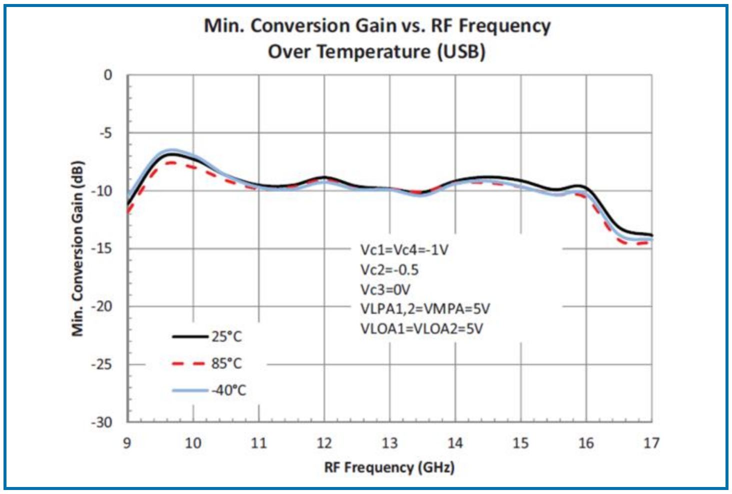
Nominal Operating Parameters

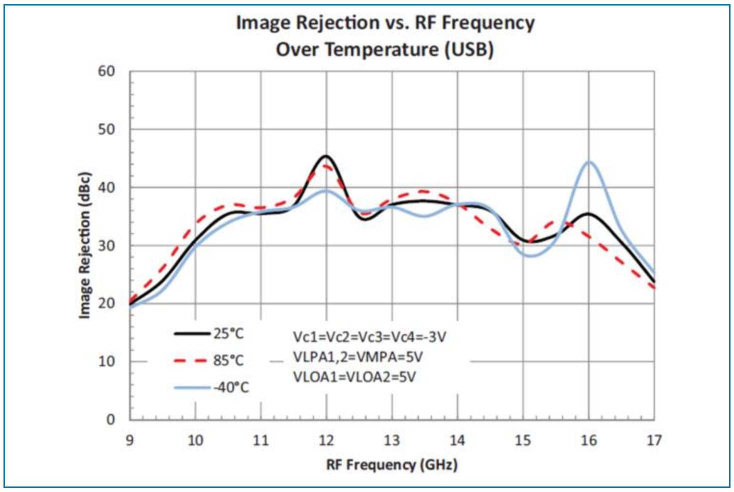
Parameter	Specification			Unit	Condition
	Min	Typ	Max		
General Performance					
RF Frequency	12		16	GHZ	
LO Frequency	8		20	GHZ	
IF Frequency	DC		4	GHZ	
LO input Drive	-1	0	+5	dBm	
Conversion Gain (Max.)	20	23	24	dB	
Conversion Gain (Min.)	-9	-10	-11	dB	
NF (max. Gain)		11	13	dB	
NF (min. Gain)		17	21	dB	
OIP3 (max. Gain)	25	28		dBm	
OIP3 (min. Gain)	9	12		dBm	
Image Rejection	15	20		dBc	
LO Leakage at RF-Port (Maximum Gain)		-5	5	dBm	With IQ bias
LO Return Loss		10		dB	
RF Return Loss		10		dB	
V_D		5		V	
I_D		380	500	mA	
VVA	-4		0	V	

Typical Electrical Performance

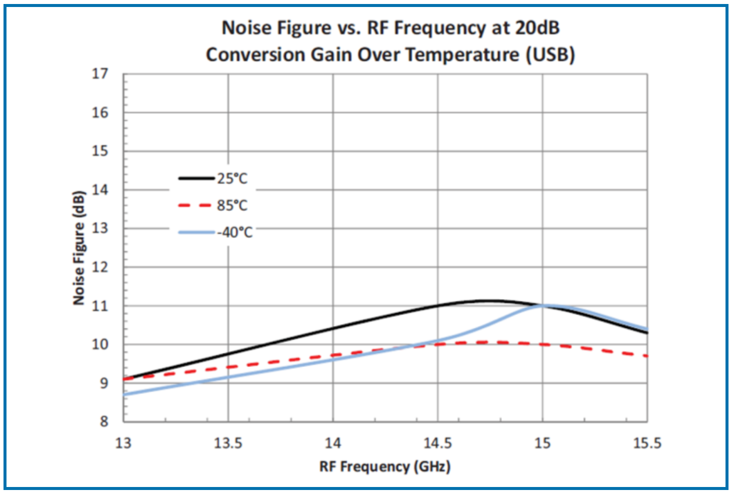
Measurements performed with I and Q (IF) ports connected to an external 90° Hybrid, LO Power = 0dBm and IF = 2.5GHz, -10dBm unless otherwise stated

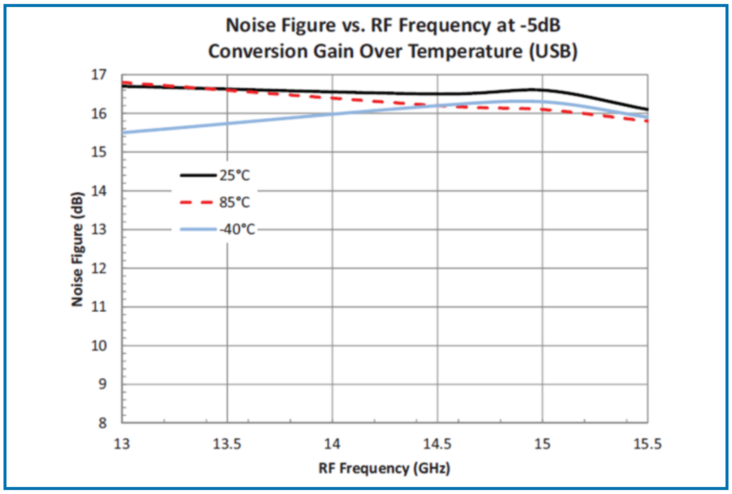


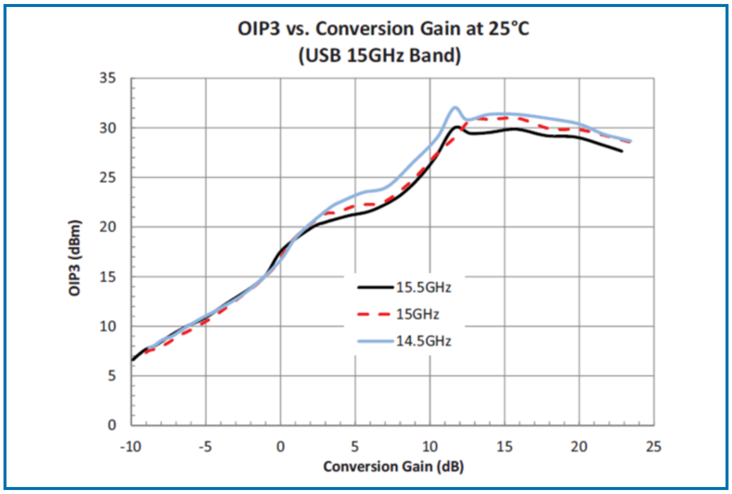


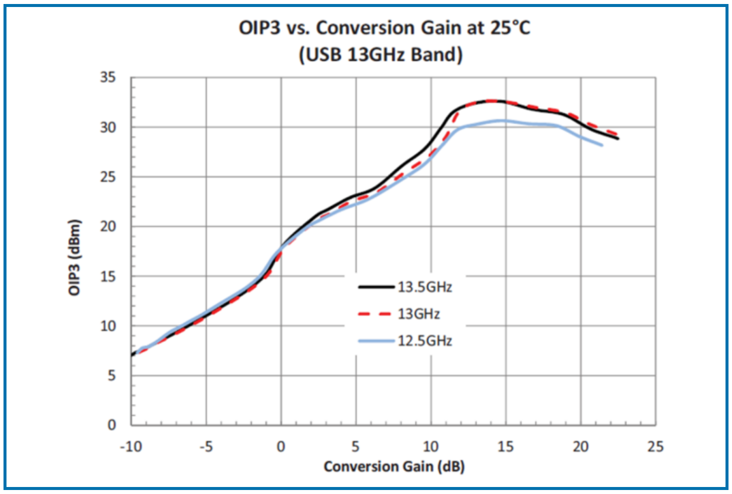


Typical Electrical Performance (continued)

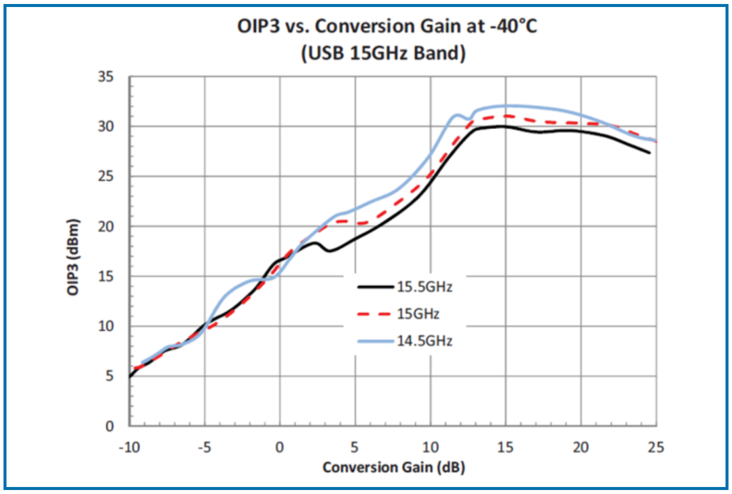


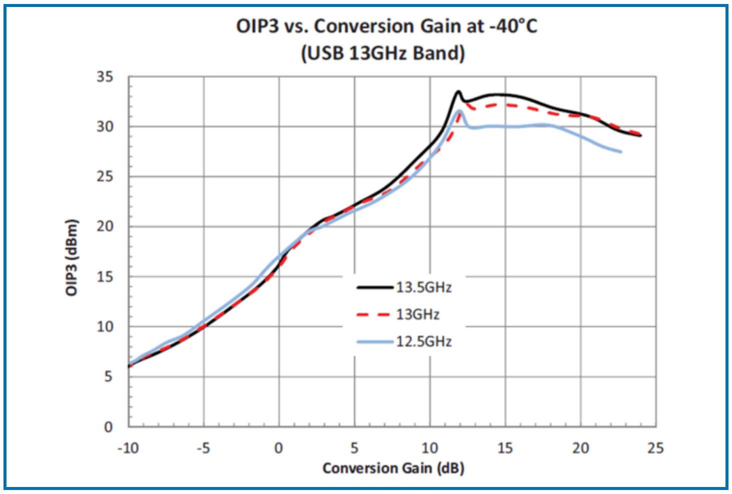


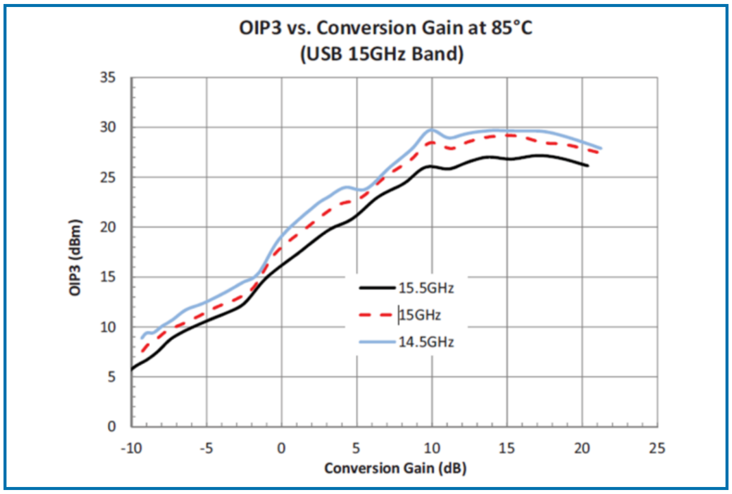


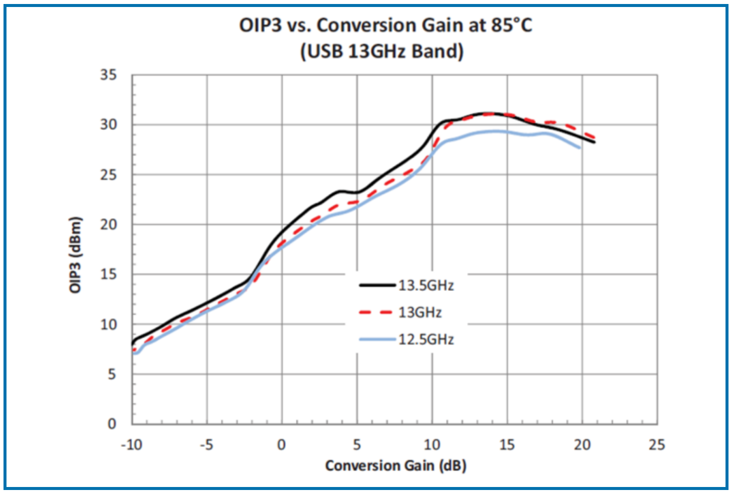


Typical Electrical Performance (continued)

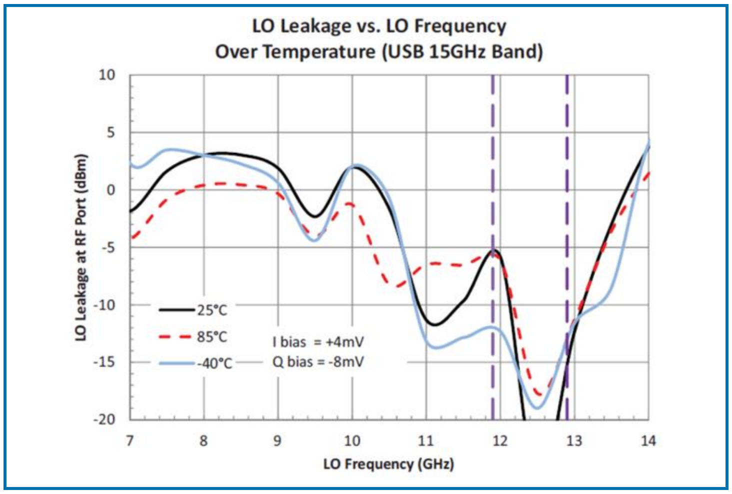


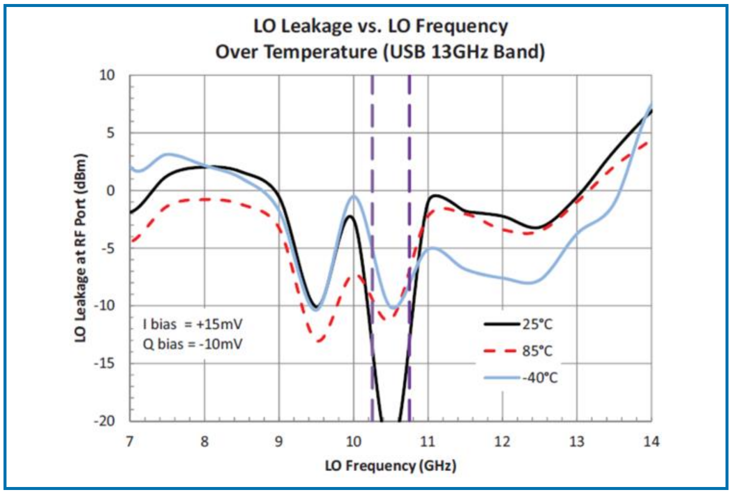


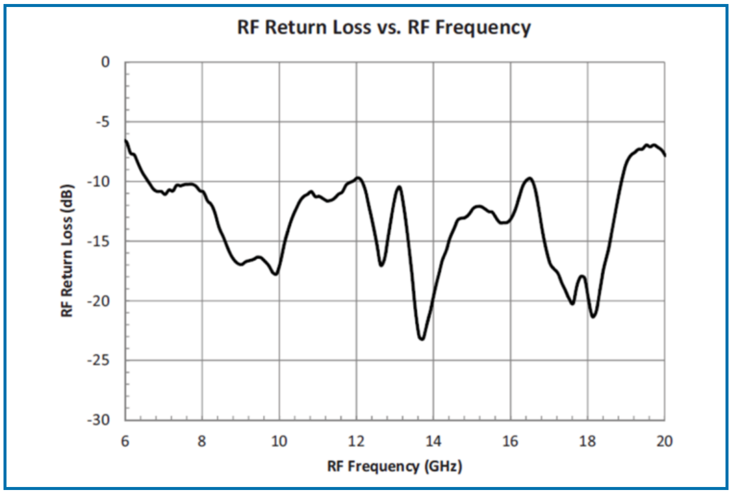


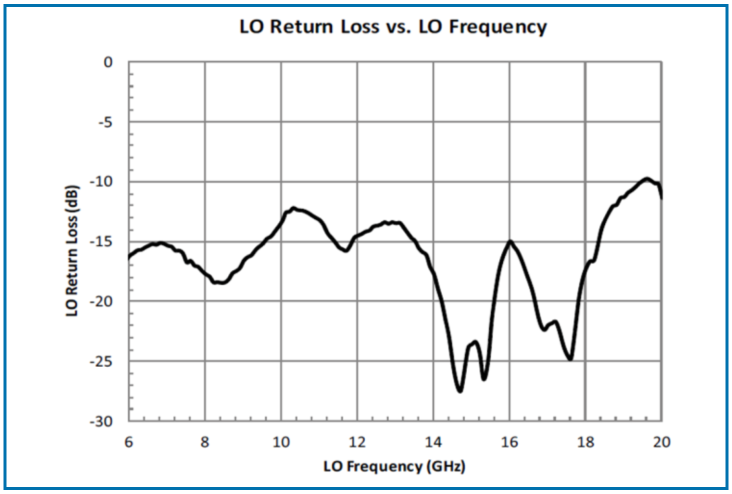


Typical Electrical Performance (continued)









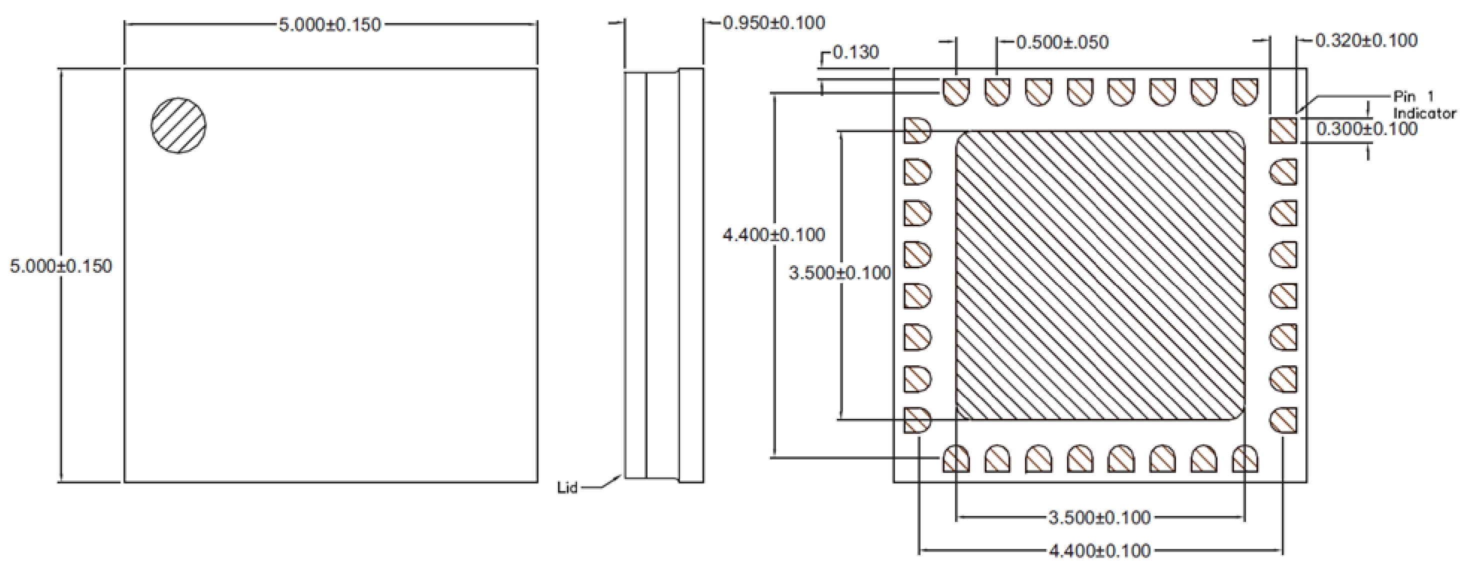
Typical Bias Sequence and Gain Control

Optimum linearity versus gain is achieved using sequential bias. At maximum gain (V_C1 ,V_C4), V_C2 and V_C3 are set at -4V. (V_C1 ,V_C4), V_C2 and V_C3 are biased in sequence. The first dynamic range is achieved by setting V_C2 and V_C3 at -4V and varying (V_C1 ,V_C4) over the (-4V to -1.25V) range as shown in the table below. Similarly second dynamic range is achieved by setting (V_C1 ,V_C4) at -1V, setting V_C3 to -4V and varying V_C2 over the (-2.5V to -1.25V) range. Finally third dynamic range is achieved by setting (V_C1 ,V_C4) and V_C2 at -1V, and varying V_C3 over the (-2.5V to -1V) range.

Bias Sequence 1 (Typical)

	Gmax																		Gmin
VC1, VC4	-4	-2.5	-2.25	-2	-1.75	-1.5	-1.25	-1	-1	-1	-1	-1	-1	-1	-1	-1	-1	-1	-1
VC2	-4	-4	-4	-4	-4	-4	-4	-2.5	-2.25	-2	-1.75	-1.5	-1.25	-1	-1	-1	-1	-1	-1
VC3	-4	-4	-4	-4	-4	-4	-4	-4	-4	-4	-4	-4	-4	-2.5	-2.25	-2	-1.75	-1.5	-1

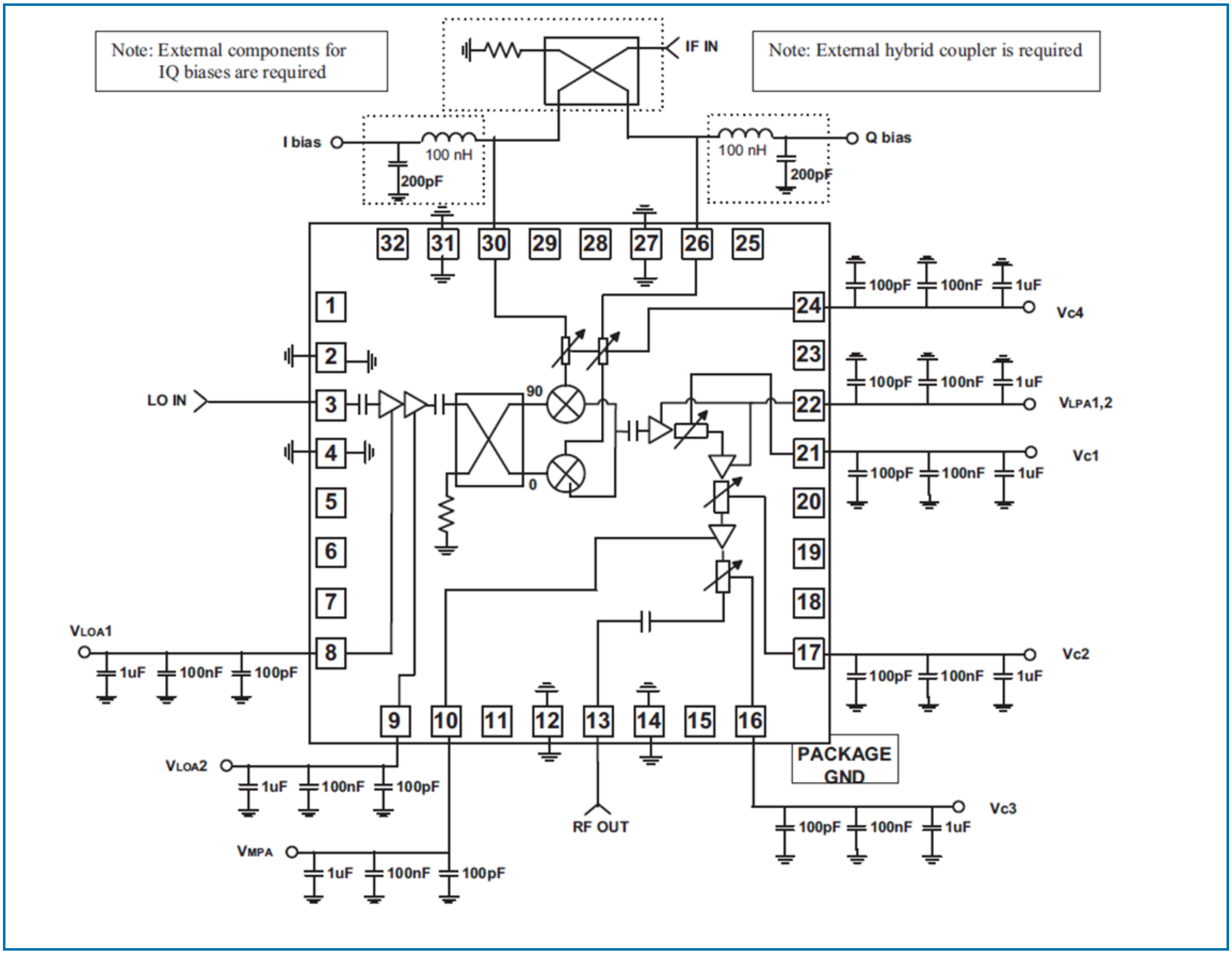
Package Outline Drawing (Dimensions in millimeters)



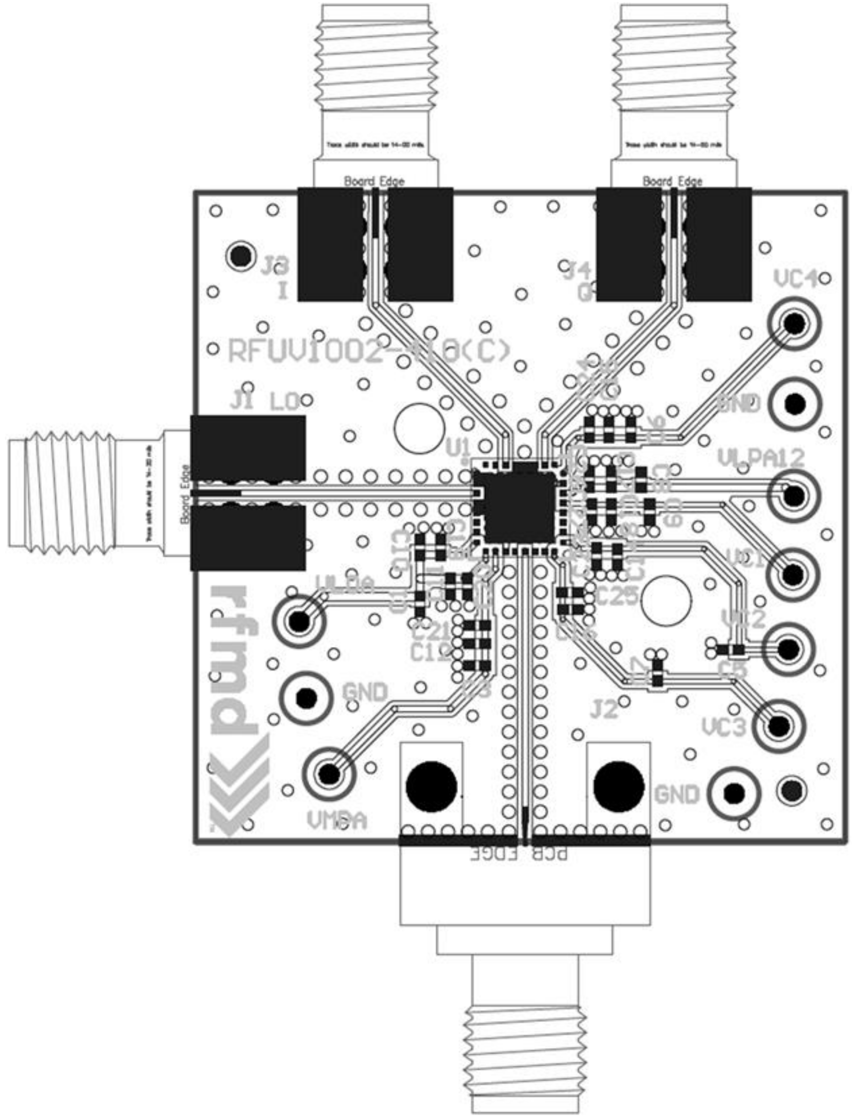
Pin Names and Descriptions

Pin	Name	Description
1	N/C	
2	GND	Ground
3	LO	Local oscillator input. AC coupled and matched to 50Ω
4	GND	Ground
5-7	N/C	
8	VLOA1	LOA stage 1 drain bias
9	VLOA2	LOA stage 2 drain bias
10	VMPA	MPA drain bias
11	N/C	
12	GND	Ground
13	RFOUT	RF output. AC coupled and matched to 50W
14	GND	Ground
15	N/C	
16	VC3	Control line number 3 (See bias sequence description)
17	VC2	Control line number 2 (See bias sequence description)
18-20	N/C	
21	VC1	Control line number 1 (See bias sequence description)
22	VLPA1, VLPA2	LPA stage 1,2 drain bias
23	N/C	
24	VC4	Control line number 4 (See bias sequence description)
25	N/C	
26	Q	IF Q input
27	GND	Ground
28-29	N/C	
30	I	If I input
31	GND	Ground
32	N/C	

Application Circuit Block Diagram



Evaluation Board Layout



Test Condition	
LO Power	0dBm
IF Power	-10dBm
VLOA1, VLOA2	5V
VLPA1, VLPA2, VMPA	5V
(V_C1, V_C4), V_C2, V_C3	-4V to 0V

Sub-Band Frequency Ranges	
Band	**Frequency Range**
10GHz	10GHz to 10.5GHz
11GHz	10.7GHz to 11.7GHz
13GHz	12.75GHz to 13.25GHz
15GHz	14.4GHz to 15.4GHz

Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
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Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.

Как с нами связаться

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